

COMPLEMENTARY SILICON POWER TRANSISTOR

Features

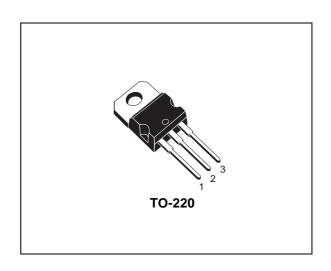
STmicroelectronics PREFERRED SALESTYPES

Applications

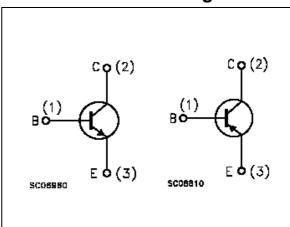
- SWITCHING APPLICATIONS
- LINEAR APPLICATIONS

Description

The BD243C device is a silicon Epitaxial-Base NPN transistor mounted in Jedec TO-220 plastic package. It's intend for use in medium power linear and switching applications. The complementary PNP type is BD244C.



Internal Schematic Diagram



Order Codes

Part Number	Marking	Package	Packing
BD243C	BD243C	TO-220	TUBE
BD244C	BD244C	TO-220	TUBE

1 Absolute Maximum Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value		Unit		
		BD243C (NPN)	BD244C (PNP)			
V _{CBO}	Collector-Base Voltage (I _E = 0)	100		V		
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	100		(I _B = 0) 100		V
V _{EBO}	Collector-Base Voltage (I _C = 0)	5		V		
I _C	Collector Current	6		Α		
I _{CM}	Collector Peak Current	1	0	Α		
I _B	Base Current 2		Α			
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$ 65		5	W		
T _{STG}	Storage Temperature	-65 to 150		°C		
T _J	Max. Operating Junction Temperature 150		°C			

For PNP types voltage and current values are negative

BD243C - BD244C 2 Electrical Characteristics

2 Electrical Characteristics

Table 2.Electrical Characteristics ($T_{CASE} = 25^{\circ}C$; unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = rated V _{CEO}				0.4	mA
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = 60 V				0.7	μA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V				1	mA
V _{CEO(sus)} Note 1	Collector-Emitter Sustaining Voltage $(I_B = 0)$	I _C = 30 mA		100			V
V _{CE(sat)} Note 1	Collector-Emitter Saturation Voltage	I _C = 6 A I _B	₃ = 1 A			1.5	V
V _{BE} Note 1	Base-Emitter Voltage	I _C = 6 A I _B	₃ = 1 A			2	V
h _{FE} Note 1	DC Current Gain	$I_C = 0.3 \text{ mA}$ V_{CE} $I_C = 3 \text{ A}$ V_{CE}	·	30 15			
h _{fe}	Small Signal Current Gain	$I_C = 0.5 \text{ A} V_{CE} = 10 \text{ V} f = 0.5 \text{ A} V_{CE} = 4 \text{ V} f = 0.5 \text{ A} V_{CE} = 4 \text{ V} f = 0.5 \text{ A} V_{CE} = $		3 20			

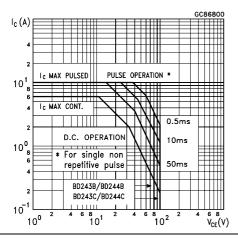
Note: 1 Pulsed duration = 300 μ s, duty cycle \leq 2%.

For PNP types voltage and current values are negative

2 Electrical Characteristics BD243C - BD244C

2.1 Typical characteristics

Figure 1. Safe Operating Area

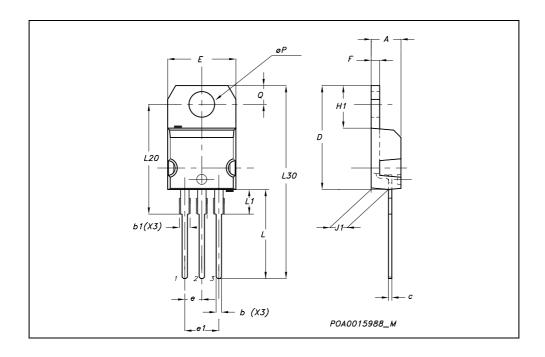


3 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 MECHANICAL DATA

DIM.	mm.			inch			
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.15		1.70	0.045		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.60		0.620	
Е	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.052	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
øΡ	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	



BD243C - BD244C 4 Revision History

4 Revision History

Date	Revision	Changes
13-Sep-2005	4	New datasheet according to MLD-PWR/05/1267 New template

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4 Revision History BD243C - BD244C

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